

140 COMMERCE DRIVE MONTGOMERYVILLE, PA 18936-1013 PHONE: (215) 631-9840 FAX: (215) 631-9855

#### RF & MICROWAVE TRANSISTORS UHF COMMUNICATIONS APPLICATIONS

#### Features

- 400 MHz
- 28 VOLTS
- **P**<sub>OUT</sub> = 25 WATTS
- $G_P = 9 \text{ dB GAIN MINIMUM}$
- EMITTER BALLASTED
- METAL/CERAMIC PACKAGE
- INTERNAL INPUT MATCHING
- REFRACTORY/GOLD METALIZATION

## **DESCRIPTION:**

The MS1527 is a gold metallized epitaxial silicon NPN planar transistor using diffused emitter ballast resistors for superior ruggedness.

The MS1527 can withstand 20:1 VSWR under rated operating conditions and is internally input matched to optimize power gain and efficiency over the band.

# PIN CONNECTION 4 1. Collector 2. Emitter 3. Base 4. Emitter

# ABSOLUTE MAXIMUM RATINGS (Tcase = 25°C)

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	60	V
V <sub>CEO</sub>	Collector-Emitter Voltage	30	V
V <sub>EBO</sub>	Emitter-Base Voltage	3.5	V
Ι <sub>c</sub>	Device Current	3.0	Α
P <sub>DISS</sub>	Power Dissipation	70	W
TJ	Junction Temperature	+200	°C
T <sub>STG</sub>	Storage Temperature	-65 +150	°C

## **Thermal Data**

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**MS1527** 



# MS1527

# ELECTRICAL SPECIFICATIONS (Tcase = 25°C) STATIC

Symbol	Tast Conditions	Value			Unit	
Symbol				Typ.	Max.	Unit
BV <sub>CBO</sub>	l <sub>c</sub> = 50 mA	$I_E = 0mA$	60			V
BV <sub>EBO</sub>	I <sub>E</sub> = 5 mA	I <sub>c</sub> = 0 mA	3.5			V
BV <sub>CES</sub>	l <sub>c</sub> = 50 mA	$V_{BE} = 0 V$	60			V
I <sub>сво</sub>	$V_{CB} = 30 V$	$I_E = 0 mA$			3.0	mA
HFE	$V_{CE} = 5 V$	I <sub>C</sub> = 500 A	10	30	120	

#### DYNAMIC

Symbol	Tost Conditions		Value		Unit		
Symbol		Test conditions		Min.	Typ.	Max.	Onit
Pout	f = 400 MHz	$V_{CC} = 28 V$	Pin = 3.15W	25			w
η <sub>c</sub>	f = 400 MHz	$V_{CC} = 28 V$		50	55		%
G <sub>P</sub>	f = 400 MHz	$V_{CC} = 28 V$		9.0	10.5		dB
VSWR	f = 400 MHz	$V_{cc} = 28 V$		20:1			
Сов	f = 1 MHz	$V_{CB} = 28V$				30	pF

# **IMPEDANCE DATA**

FREQ	Z <sub>IN</sub> (Ω)	$Z_{CL}(\Omega)$
225 MHz	1.40 + j 2.5	7.55 + j 0.0
275 MHz	1.25 + j 3.3	7.5 - j 0.05
300 MHz	1.10 + j 4.0	7.5 - j 1.00
350 MHz	1.10 + j 4.7	6.8 - j 1.15
400 MHz	1.70 + j 5.1	6.0 - j 1.30

P<sub>OUT</sub> = 25 W V<sub>CE</sub> = 28 V



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# **TYPICAL PERFORMANCE**





**MS1527** 

## PACKAGE MECHANICAL DATA

